

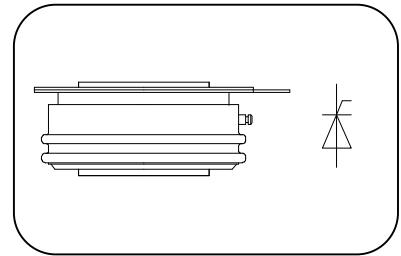
# Y30KAD

## HIGH FREQUENCY THYRISTOR

### Features:

- Interdigitated amplifying gates
- Fast turn-on and high  $dI/dt$
- Low switching losses
- Short turn-off time
- Hermetic metal cases with ceramic insulators

**$I_{T(AV)}$**       **420A**  
 **$V_{DRM}/V_{RRM}$**       **800~1400V**  
 **$t_q$**       **8~12μs**  
 **$I_{TSM}$**       **2.4KA**



### Typical Applications

- Inductive heating
- Electronic welders
- Self-commutated inverters
- AC motor speed control
- General power switching applications

SYMBOL	CHARACTERISTIC	TEST CONDITIONS	$T_f(^{\circ}C)$	VALUE			UNIT
				Min	Type	Max	
$I_{T(AV)}$	Mean on-state current	180° half sine wave 50Hz Double side cooled, $T_{hs}=55^{\circ}C$	125			420	A
$V_{DRM}$ $V_{RRM}$	Repetitive peak off-state voltage Repetitive peak reverse voltage	$V_{DRM} \& V_{RRM}$ , $tp=10ms$ $V_{DSM} \& V_{RSM} = V_{DRM} \& V_{RRM} + 100V$	125	800		1400	V
$I_{DRM}$ $I_{RRM}$	Repetitive peak off-state current Repetitive peak reverse current	$V_D = V_{DRM}$ $V_R = V_{RRM}$	125			30	mA
$I_{TSM}$	Surge on-state current	10ms half sine wave $V_R=0.6V_{RRM}$	125			2.4	KA
$I^2t$	$I^2T$ for fusing coordination					29	$A^2s \times 10^3$
$V_{TO}$	Threshold voltage		125			1.67	V
$r_T$	On-state slop resistance					1.32	mW
$V_{TM}$	Peak on-state voltage	$I_{TM}=600A$ , $F=7.0KN$	125			2.46	V
$dv/dt$	Critical rate of rise of off-state voltage	$V_{DM}=0.67V_{DRM}$	125			200	V/ $\mu$ s
$di/dt$	Critical rate of rise of on-state current	$V_{DM}=67\%V_{DRM}$ Gate pulse $t_r \leq 0.5 \mu s$ $I_{GM}=1.5A$ Repetitive	125			600	A/ $\mu$ s
$I_{rm}$	Reverse recovery current				30		A
$t_{rr}$	Reverse recovery time	$I_{TM}=400A$ , $tp=1000\mu s$ , $di/dt=-20A/\mu s$ , $V_R=50V$	125		2.5		$\mu$ s
$Q_{rr}$	Recovery charge				38	50	$\mu$ C
$t_q$	Circuit commutated turn-off time	$I_{TM}=400A$ , $tp=1000\mu s$ , $V_R = 50V$ $dv/dt=30V/\mu s$ , $di/dt=-20A/\mu s$	125	8		12	$\mu$ s
$I_{GT}$	Gate trigger current		25	30		200	mA
$V_{GT}$	Gate trigger voltage	$V_A=12V$ , $I_A=1A$		0.8		2.5	V
$I_H$	Holding current			20		250	mA
$V_{GD}$	Non-trigger gate voltage	$V_{DM}=67\%V_{DRM}$	125	0.3			V
$R_{th(j-h)}$	Thermal resistance Junction to heat sink	At 180° sine double side cooled Clamping force 7.0KN				0.055	$^{\circ}C / W$
$F_m$	Mounting force			5.3		10	KN
$T_{stg}$	Stored temperature			-40		140	$^{\circ}C$
$W_t$	Weight				80		g
Outline				KT25aT			

**Outline:**